# NSN 5961-00-722-1266

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.215 inches and 0.320 inches

## **Overall Diameter:**

Between 0.320 inches and 0.360 inches

# **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

# **Mounting Method:**

Threaded stud

# Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

#### **Thread Size:**

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown

voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

2.50 amperes source cutoff current

## Power Rating Per Characteristic:

18.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Thread Series Designator:

Unf

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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